2N5117-2N5119

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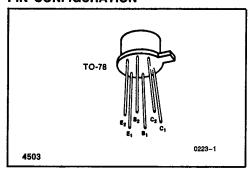
2N5117 - 2N5119Dielectrically Isolated Dual PNP General Purpose Amplifier



FEATURES

- High Gain at Low Current
- Low Output Capacitance
- Good h_{FE} Match
- Tight VBE Tracking
- Dielectrically Isolated Matched Pairs for Differential Amplifiers

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS

 (TA = 25°C unless otherwise noted)

 Collector-Base or Collector-Emitter

 Voltage (Note 1)
 -45V

 Emitter-Base Voltage (Notes 1 and 2)
 -7V

 Collector-Collector Voltage
 100V

 Collector Current (Note 1)
 10mA

 Storage Temperature Range
 -65°C to +200°C

 Operating Temperature Range
 -55°C to +175°C

 Lead Temperature (Soldering, 10sec)
 +300°C

 Power Dissipation
 ONE SIDE 250mW
 BOTH SIDES 500mW

 Derate above 25°C
 1.67mW/°C
 3.33mW/°C

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ORDERING INFORMATION

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Symbol		Test Conditions			2N5117 2N5118		2N5119		Units
						Max	Min	Max	
hfE	DC Current Gain	I _C =10μA, V _{CE} =5.0V			100	300	50		
		I _C =500μA, V _{CE} =5.0V			100		50		
		I _C =10μA, V _{CE} =5.0V, T _A =-55°C			30		20		
ICBO	Collector Cutoff-Current	I _E =0, V _{CB} =30V				0.1		0.1	nA
				T _A = 150°C		0.1		0.1	μΑ
EBO	Emitter Cutoff Current	I _C =0, V _{EB} =5.0V				0.1		0.1	nΑ
lc ₁ -c ₂	Collector-Collector Leakage	V _{CC} =100V	· · · · ·			5.0		5.0	pΑ
GBW	Current Gain Bandwith Product (Note 4)	I _C =500μA, V _{CE} =10V			100		100		MHz
Cob	Output Capacitance (Note 4)	I _E =0, V _{CB} =5.0V, f=1MHz				0.8		8.0	
Cte	Emitter Transition Capacitance (Note 4)	I _C =0, V _{EB} =0.5V, f=1MHz				1.0		1.0	pF
C _{C1} -C2	Collector-Collector Capacitance (Note 4)	V _{CC} =0, f=1MHz				0.8		0.8	
V _{CEO(sust)}	Collector-Emitter Sustaining Voltage	I _C =1.0mA, I _B =0			45		45		٧
NF	Narrow Band Noise Figure (Note 4)	I _C =10μA, V _{CE} =5.0V BW=200Hz				4.0		4.0	dΒ
BV _{CBO}	Collector Base Breakdown Voltage	I _C =10μA, I _E =0			45		45		٧
BVEBO	Emitter Base Breakdown Voltage	I _E =10μA, I _C =0			7.0		7.0		٧

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MATCHING CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Cumbal	Parameter	Test Conditions		2N5117		2N5118		2N5119	
Symbol		rest Conditions			Min				
h _{FE1} /h _{FE2}	DC Current Gain Ratio	I _C =10μA to 500μA, V _{CE} =5V		9 1.0					
	(Note 3)	I _C = 10μA, V _{CE} = 5.0V			0.85	1.0	0.8	1.0	
VBE1-VBE2	Base-Emitter Voltage Differential	I _C =10μA to 500μA, V _{CE} =5V		3.0					mV
' -		IC=10μA, VCF=5.0V				5.0	<u> </u>	5.0	
B1-1B2	Base Current Differential)	15		40	nΑ
Δ(V _{BE1} -V _{BE2})/ΔΤ	Base Voltage Differential Change with Temperature	$T_A = -55^{\circ}C \text{ to } + 125^{\circ}C$	5°C	3.0		5.0		10	μ V /°C
Δ(I _{B1} -I _{B2})/ΔΤ	Base-Current Differential Change with Temperature	$T_A = -55^{\circ}C \text{ to } + 125^{\circ}C$	5°C	0.3		0.5		1.0	nA/°C

NOTES: 1. Per transistor.

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- For the transition.
 The reverse base-to-emitter voltage must never exceed 7.0 volts and the reverse base-to-emitter current must never exceed 10μA.
 Lower of two h_{FE} readings is defined as h_{FE}.
 For design reference only, not 100% tested.

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